

WS3A008065A

Silicon Carbide Schottky Diode

V _{RRM}	=	650	V
I _F (T _C ≤135°C)	=	11	Α
Qc	=	22	nC

Features

- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on V_F
- Temperature-independent Switching
- 175°C Operating Junction Temperature

Benefits

- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor drive, PV Inverter, Wind Power Station

Package





Part Number	Package	Marking	
WS3A008065A	TO-220-2	WS3A008065A	

Maximum Ratings

Symbol	Parameter	Value	Unit	Test Conditions	Note
V_{RRM}	Repetitive Peak Reverse Voltage	650	V	$T_C = 25^{\circ}C$	
V _{RSM}	Surge Peak Reverse Voltage	650	V	T _C = 25°C	
V_R	DC Blocking Voltage	650	٧	$T_C = 25^{\circ}C$	
l _F	Forward Current	24 11 8	А	T _C ≤ 25°C T _C ≤ 135°C T _C ≤ 153 °C	
I _{FSM}	Non-Repetitive Forward Surge Current	72	Α	$T_C = 25^{\circ}C$, $t_p = 8.3$ ms, Half Sine Wave	
P _{tot}	Power Dissipation	107	W	T _C = 25°C	Fig.3
Tc	Maximum Case Temperature	153	°C		
T _J , T _{STG}	Operating Junction and Storage Temperature	-55 to 175	°C		
	TO-220 Mounting Torque	1	Nm	M3 Screw	



Electrical Characteristics

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note	
V _F	Forward Voltage	1.4	1.65	V	I _F = 8A, T _J = 25°C	Fig 1	
		1.7	2.3		I _F = 8A, T _J = 175°C	Fig.1	
I _R	Reverse Current	1	20		V _R = 650V, T _J = 25°C	F: 0	
		5	100	μA	$V_R = 650V, T_J = 175^{\circ}C$	Fig.2	
		520			$V_R = 0V, T_J = 25^{\circ}C, f = 1MHz$		
С	Total Capacitance	50	/	pF	$V_R = 200V, T_J = 25^{\circ}C, f = 1MHz$	Fig.5	
			41	41		$V_R = 400V$, $T_J = 25^{\circ}C$, $f = 1MHz$	
Qc	Total Capacitive Charge		,		$V_R = 650V, I_F = 8A$	F:- 4	
		Total Capacitive Charge 22	/	nC	di/dt = 200A/μs, T _J = 25°C	Fig.4	

Thermal Characteristics

Symbol	Parameter	Тур.	Unit	Note
R _{θJC}	Thermal Resistance from Junction to Case	1.4	°CM	Fig.6
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	80	°C/W	
T _{sold}	T _{sold} Soldering Temperature		°C	

Typical Performance

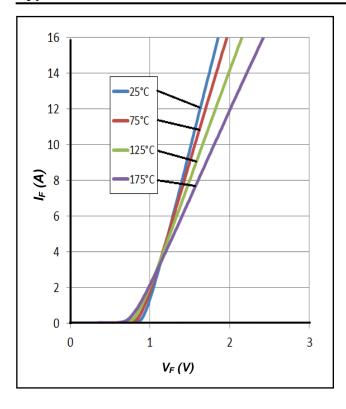


Figure 1. Forward Characteristics

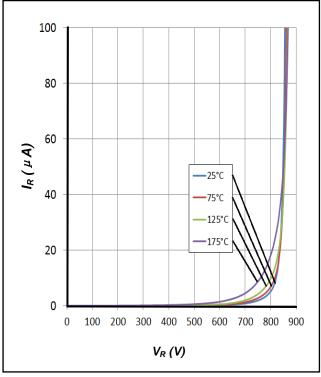
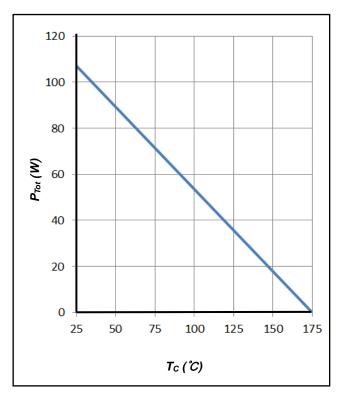


Figure 2. Reverse Characteristics

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Typical Performance



25 20 15 5 0 10 200 300 400 500 600 V_R (V)

Figure 3. Power Derating

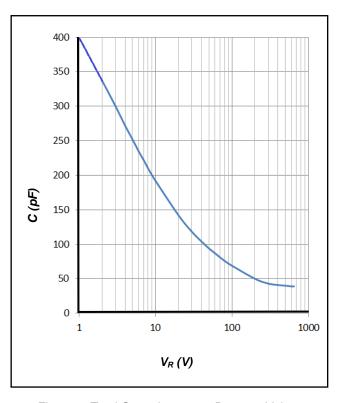


Figure 5. Total Capacitance vs. Reverse Voltage

Figure 4. Total Capacitive Charge vs. Reverse Voltage

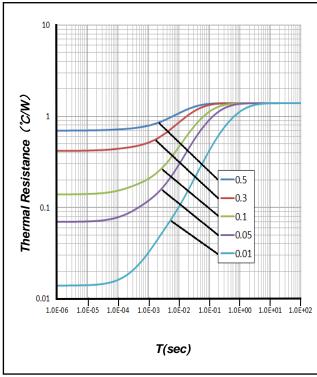
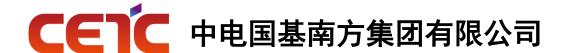
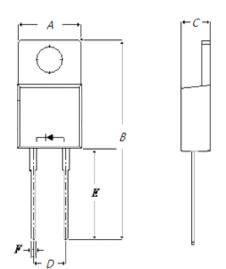


Figure 6. Transient Thermal Impedance



Package Dimensions

Package TO-220-2

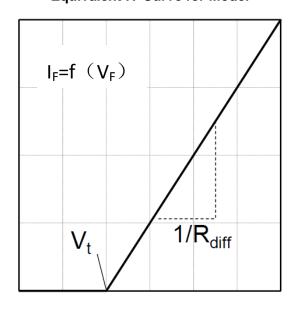




Symbol	Min. (mm)	Typ. (mm)	Max. (mm)
А	9.17	10.08	10.91
В	27.00	28.58	30.00
С	3.89	4.50	5.00
D	4.20	5.10	5.80
Е	11.70	13.30	14.97
F	0.50	0.80	1.21

Simplified Diode Model

Equivalent IV Curve for Model



Mathematical Equation

$$V_F = V_t + I_F \times R_{diff}$$

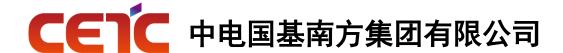
$$\begin{split} V_t &= -0.001 \times T_j + 0.9674 \ [V] \\ R_{diff} &= 1 \times 10^{-6} \times T_j^2 + 1 \times 10^{-4} \times T_j + 0.0543 \ [\Omega] \end{split}$$

Note:

Tj = Diode Junction Temperature In Degrees Celsius, valid from 25°C to 175°C

I_F= Forward Current

Less than 16A



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